

Tuning growth of faceted $\text{Na}_3\text{Zr}_2(\text{SiO}_4)_2\text{PO}_4$ via sintering holding time and its effect on ionic conductivity

Man Kit Chong, Zalita Zainuddin*, Fatin Saiha Omar, Mohammad Hafizuddin Hj Jumali

Department of Applied Physics, Faculty of Science and Technology, Universiti Kebangsaan Malaysia,
43600 UKM Bangi, Selangor Darul Ehsan, Malaysia.

***Corresponding author:**

Email: zazai@ukm.edu.my

APPENDIX: Supplementary materials

Table S1. Unit cell parameters and cell volume of NZSP samples with different sintering holding time obtained by Pawley refinements.

Sintering time / h	$a / \text{\AA}$	$b / \text{\AA}$	$c / \text{\AA}$	$\beta / ^\circ$	$V / \text{\AA}^3$
6	15.71	9.084	9.207	124.0	1089
12	15.58	9.207	9.283	120.7	1145
18	15.73	9.109	9.193	124.1	1090
24	15.63	9.120	9.205	123.6	1093

* All the values are rounded to 4 s. f.